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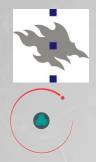


Computer simulations of Cu surface behavior before and after a breakdown event

Flyura Djurabekova, Aarne Pohjonen, Avaz Ruzibaev, Stefan Parviainen, Riikka Ruuth, Johann Muszynski, Kai Nordlund

Helsinki Institute of Physics and Department of Physics University of Helsinki

Finland

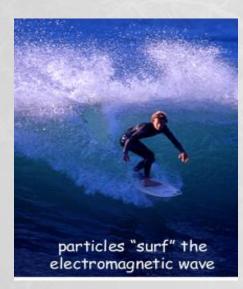


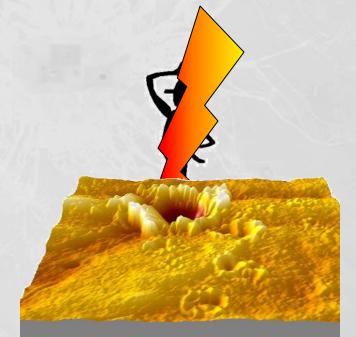


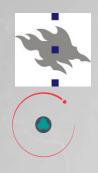
so Our vision of processes preceding a breakdown event

Multiscale/multiphysics modeling

Work function of different faces of Cu polycrystallites
Voids under the surface: a possible source of protrusions
What happens to the surface after the impact?



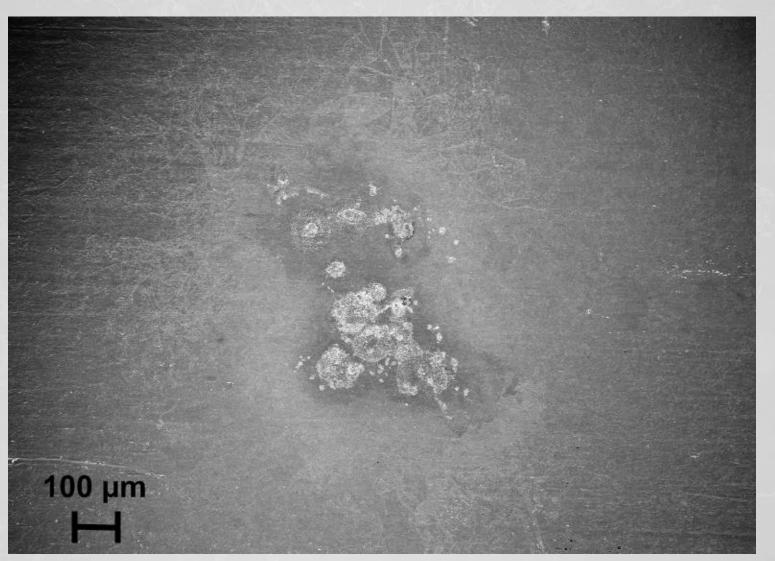


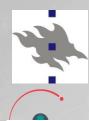




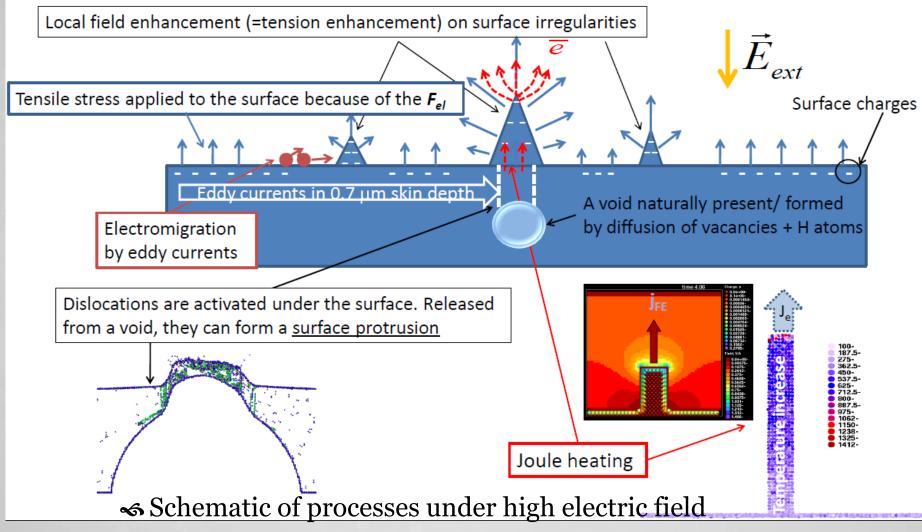
Setup to measure dc sparks on a flat cathode surface (CERN)

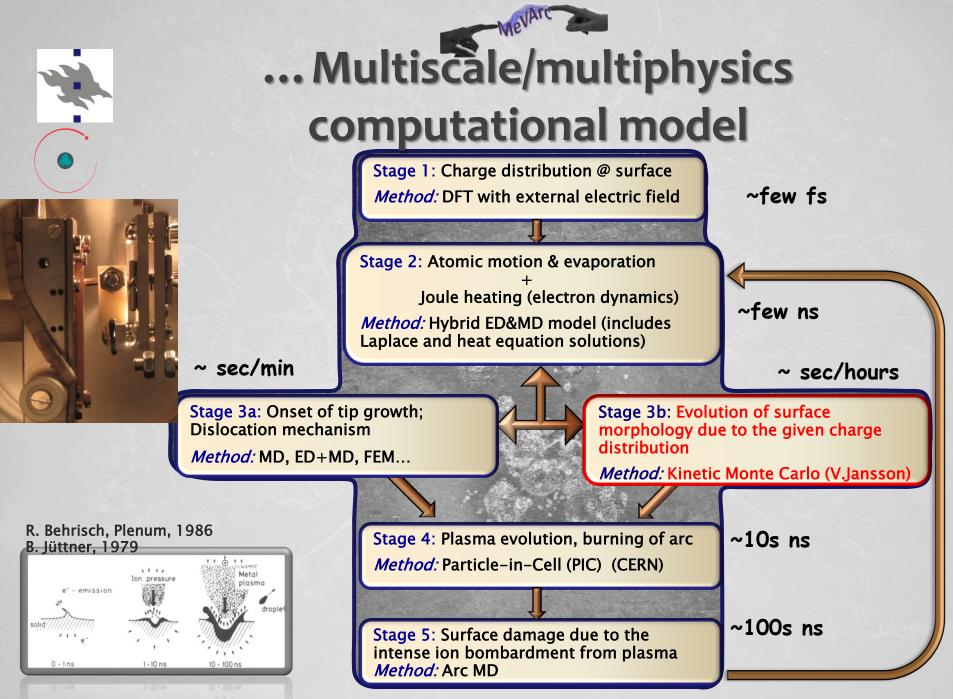


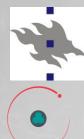




Our vision of processes prior to breakdown event







Evolution of a tip placed on Cu surface

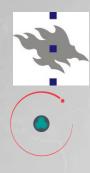
time 0.0041 p 0.0e+00-

 We developed a novel approach to follow the dynamic evolution of partial charge on surface atoms by combining the MD and classical ED (solving Laplace equation)

The dynamics of atom charges follows the shape of electric field distortion on tips on the surface

Temperature on the surface tips is sufficient => atom evaporation enhanced by the field can supply neutrals to build up the plasma densities above surface.

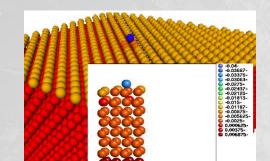
Details in F. Djurabekova, S. Parviainen, A. Pohjonen and K. Nordlund, PRE 83, 026704 (2011).

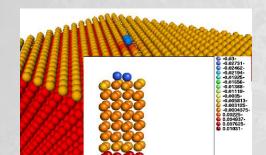


E_o=-1 GV/m

DFT calculations to validate the

charges on surface atoms

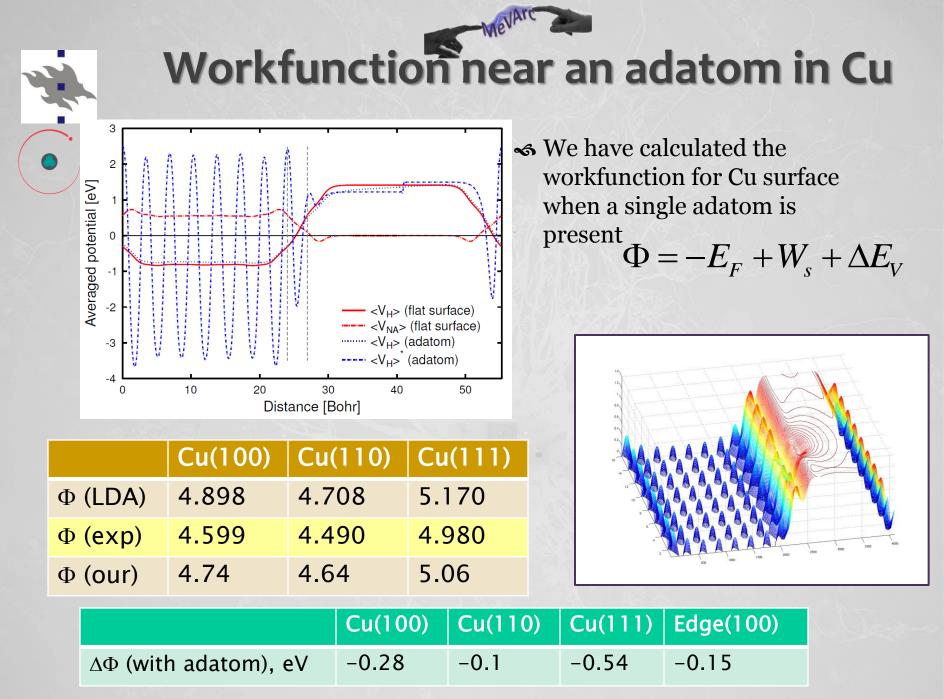


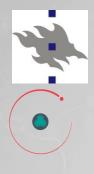


✤ DFT details:

- Code: SIESTA
- For exchange and correlations functionals the Perdew, Burke and Ernzerhof scheme of Generalized gradient approximation (GGA)
- Slab organized in 8 layers+ 8 layers of vacuum
- External field is added to calculate the electrostatic potential in the vacuum

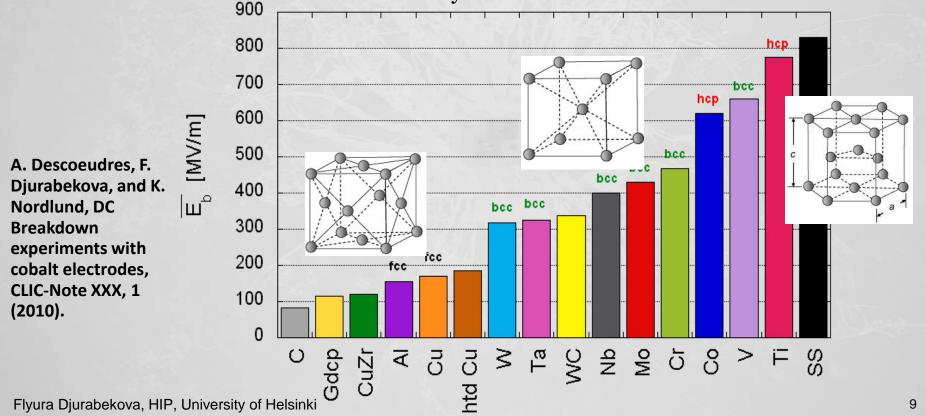
15 30	An adatom		Double adatom	
	DFT, SIESTA	ED&MD	DFT, SIESTA	ED&MD
Charge (q _e) per adatom	-0.034	-0.043	-0.025	-0.035





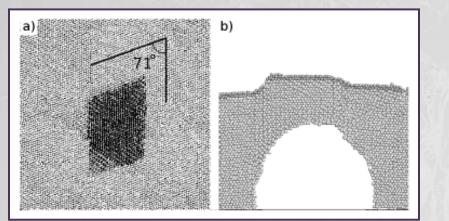
What are the field emitters? Why do we look for dislocations?

Solution structure of metals. In FCC (face-centered cubic) the dislocation are the most mobile and HCP (hexagonal close-packed) are the hardest for dislocation mobility.

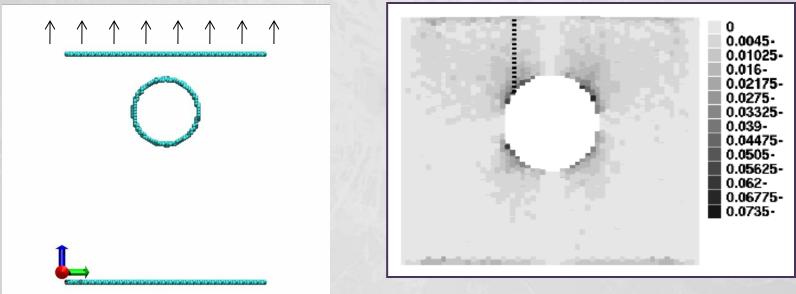




A void hypothesis as a lattice irregularity



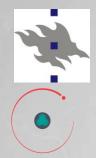
Solution We simulated a void near {110} Cu surface , when the high tensile stress is applied on the surface. Bottom is fixed, lateral boundary allowed to move in z direction.



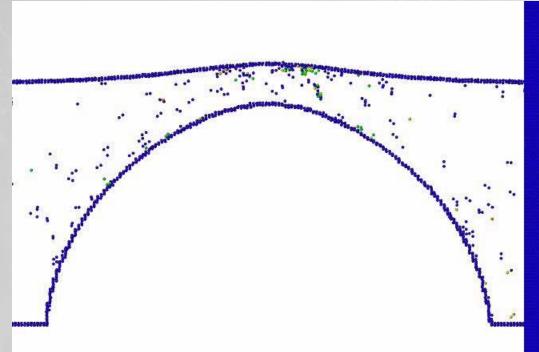
A. Pohjonen, F. Djurabekova, et al., Dislocation nucleation from near surface void under static tensile stress on surface in Cu, *Jour. Appl. Phys.* 110, 023509 (2011).

Flyura Djurabekova, HIP, University of Helsinki





Switching on the electric field above the surface

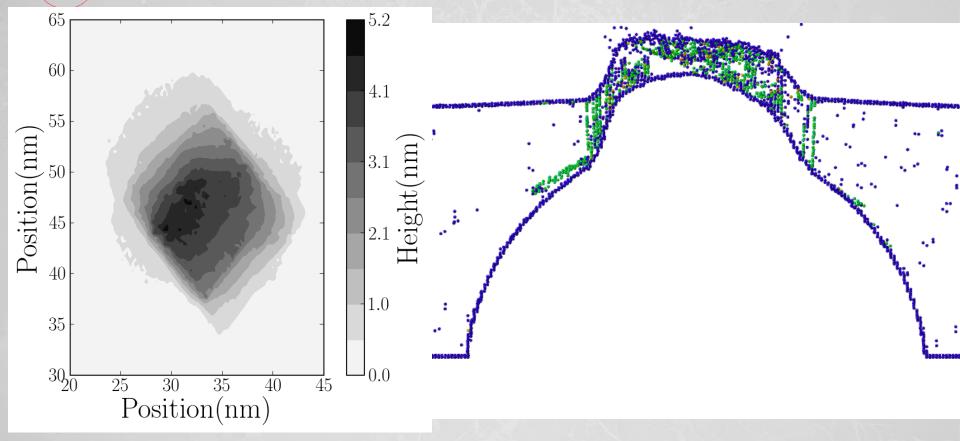


 ✓ We have now finished the analysis of the behavior of a void under tensile stress due to the electric field (Simulations now done with the hybrid &D-MD code, where the electric field effect is accounted explicitly)

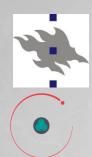
[A. S. Pohjonen, S. Parviainen, T. Muranaka, and F. Djurabekova, Journal of Appl. Physics 114, 033519 (2013)] Flyura Djurabekova, HIP, University of Helsinki



"Catastrophic" growth of a protrusion at the void

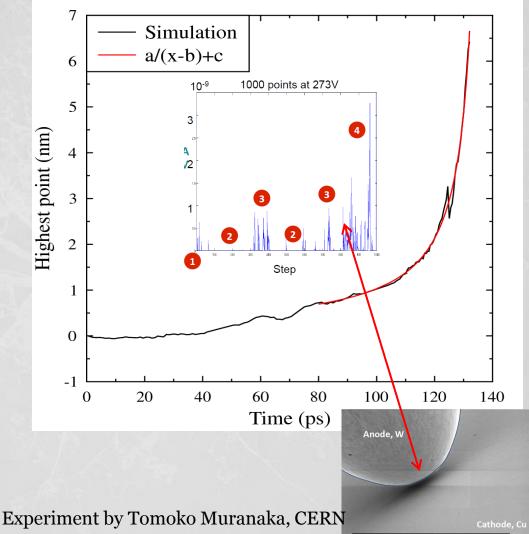


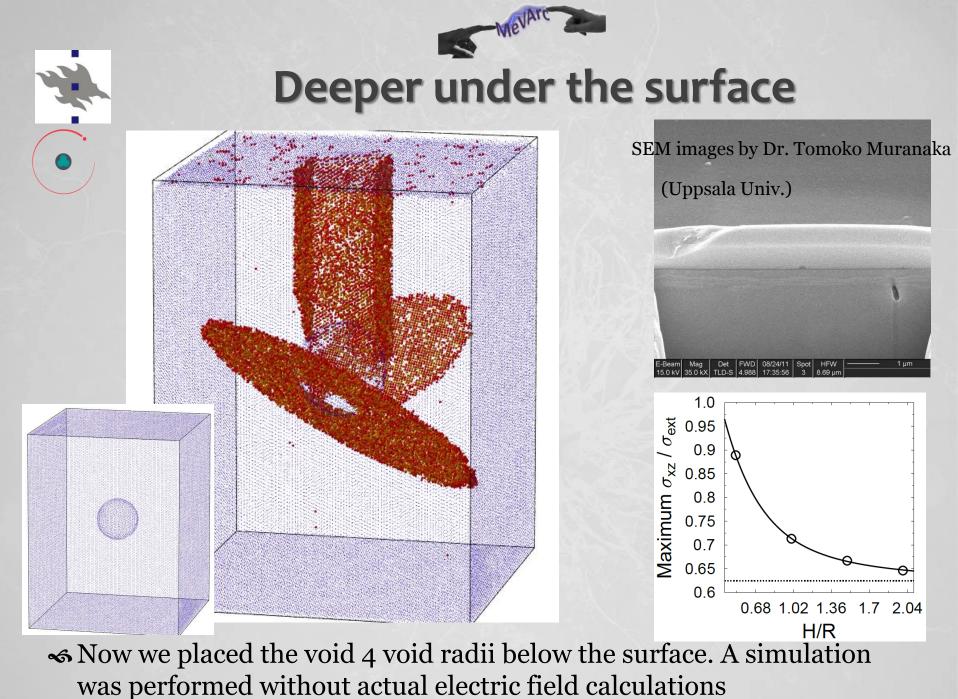
s. the top view and a slice of the system at time t = 130 ps when the fully developed protrusion is clearly visible.
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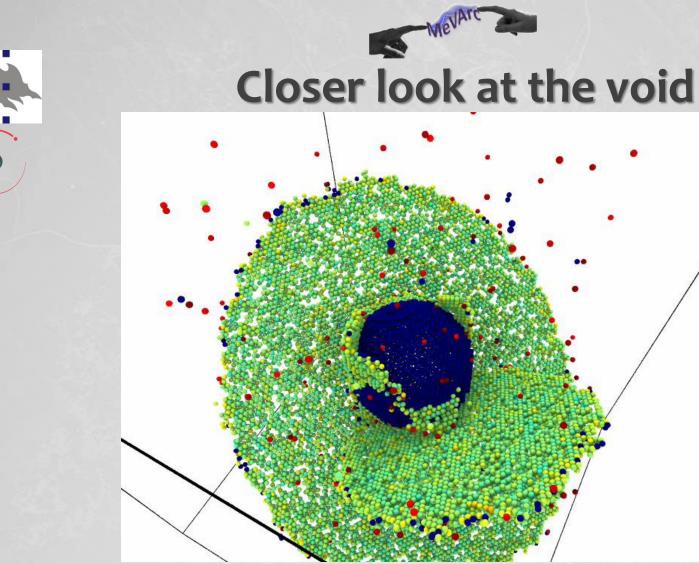


The "catastrophic" growth of a protrusion in the presence of the field

← The analysis of the protrusion height increase shows an asymptotic character. Once it starts growing, the self-reinforcing effect of the field enhancement around the tip of the protrusion causes the increase of its height in the "catastrophic" manner







Size of the void is 4 nm, tensile stress is exaggerated, corresponding to 15 GV/m

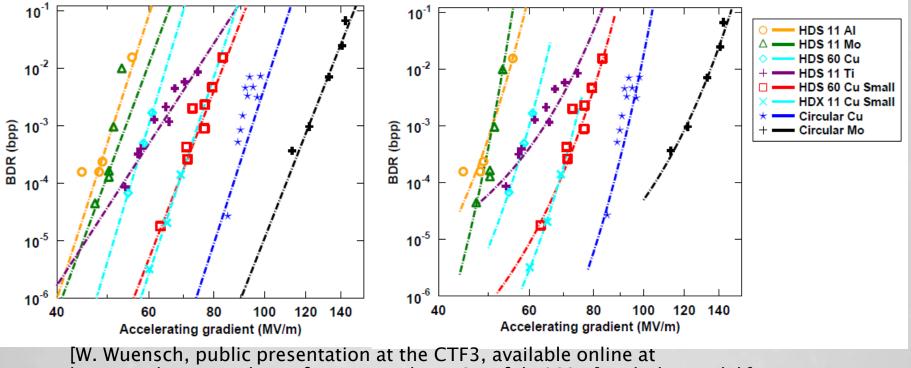
Solution However, we did not expect a prismatic loop to be punched from a Flyura Djurabekova, HIP, University of Helsinki

Dislocation-based model for electric field dependence *BDR* $\propto c = B P_0 R^{-(E - A P^{2E} A P)/kT} = c_0 e^{-E^f/kT} e^{\varepsilon_0 E^2 \Delta V/kT}$

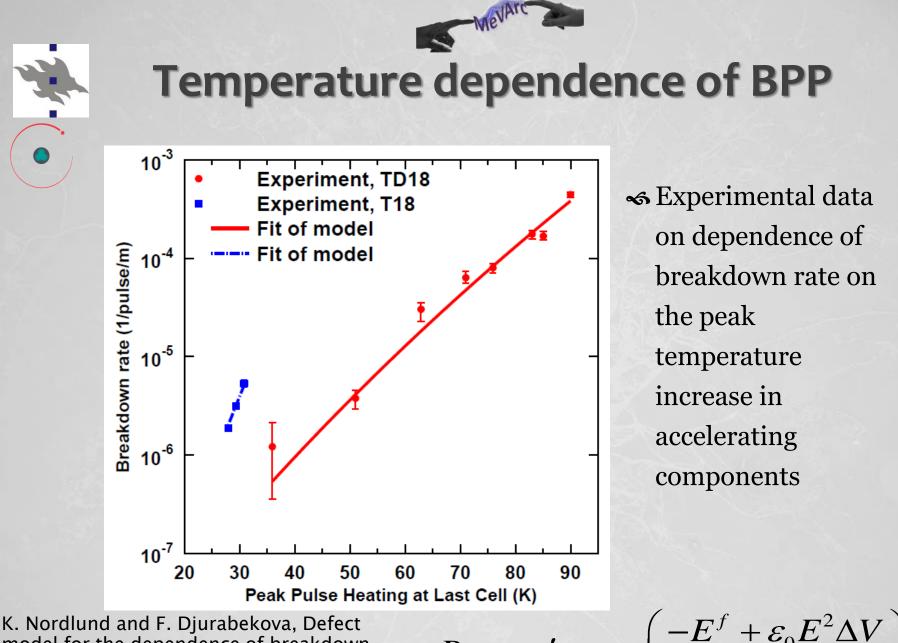
Now to test the relevance of this, we fit the experimental data
The result is:

Power law fit

Stress model fit

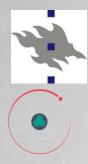


http://indico.cern.ch/conferenceDisplay.py?confld=8831.] with the model.] Flyura Djurabekova, HIP, University of Helsinki



model for the dependence of breakdown rate on external electric fields, Phys. Rev. ST-AB 15, 071002 (2012). Flyura Djurabekova, HIP, University of Helsinki

 $R_{BD} = a'c_0 \exp\left(\frac{-E^f + \varepsilon_0 E^2 \Delta V}{k_B (T_0 + \Delta T)}\right)$



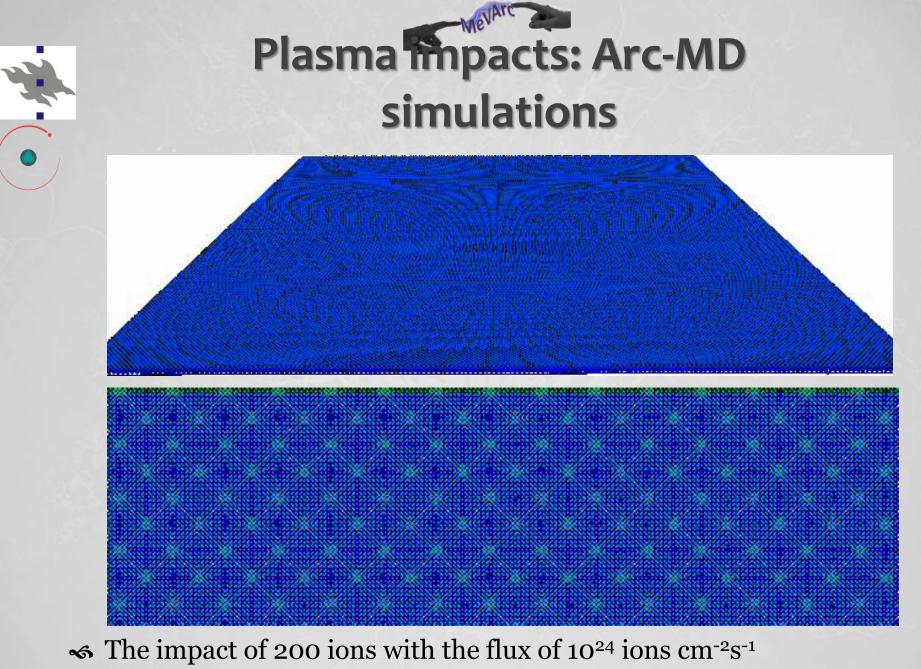
Plasma impacts on Cu surface

S As plasma ion parameters we use the results obtained in 1D plasma claculations.

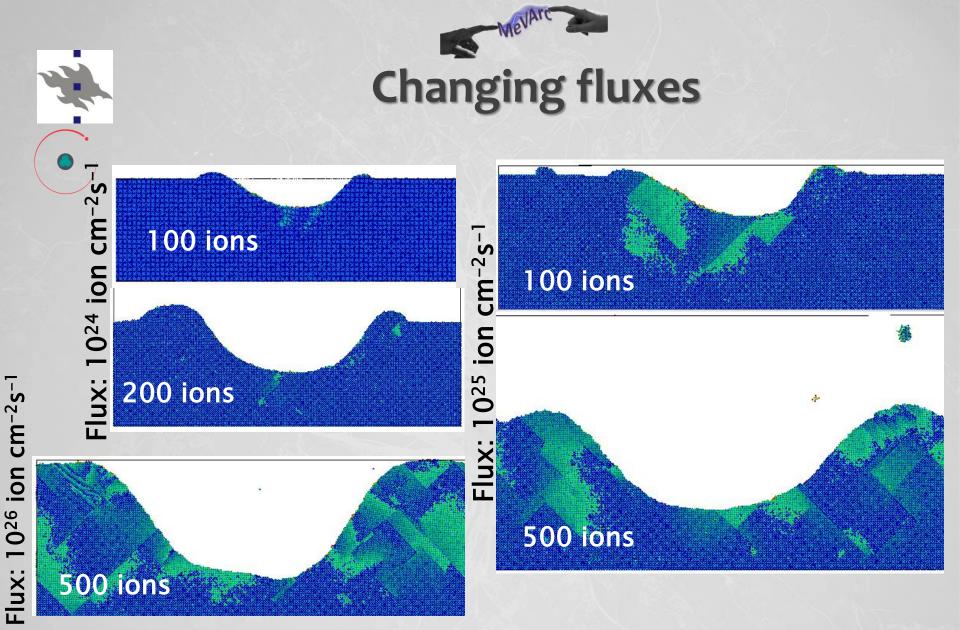
- The merging of these simulations with 2D plasma development code is still in progress.
- ✤ To assess the effect of temperature and cooling we simulated three types of surfaces:

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\checkmark Molten at melting point T_{\rm m}
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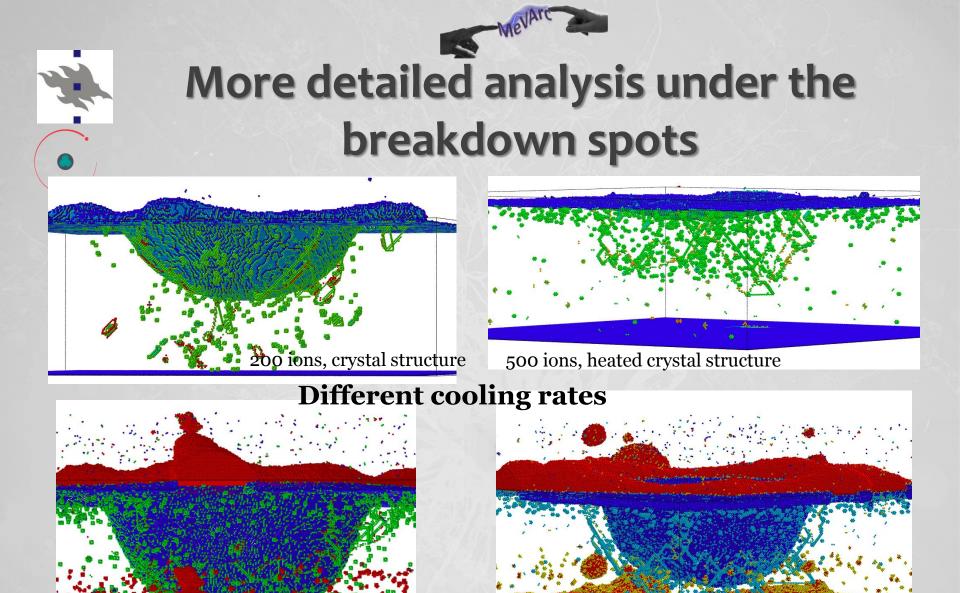
- ∞ Molten, just below T_m (undercooled liquid)
- \sim Still crystal, just below T_m (overheated crystal)
- ∽ Energy E=6 keV



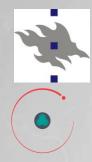
Section Energy of ions 6 keV at RT Flyura Djurabekova, HIP, University of Helsinki



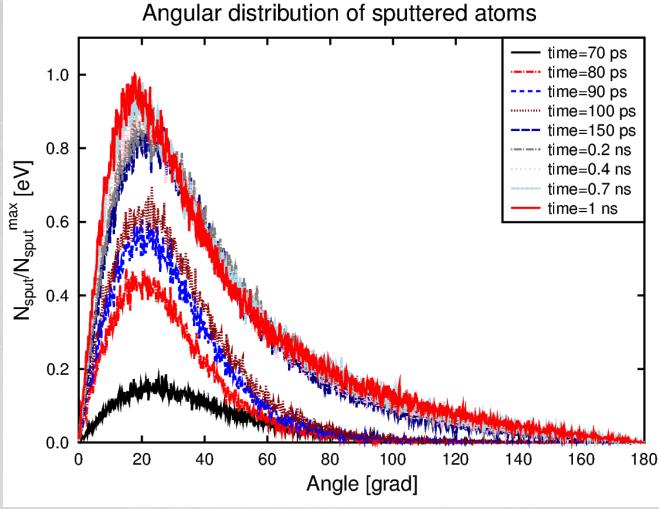
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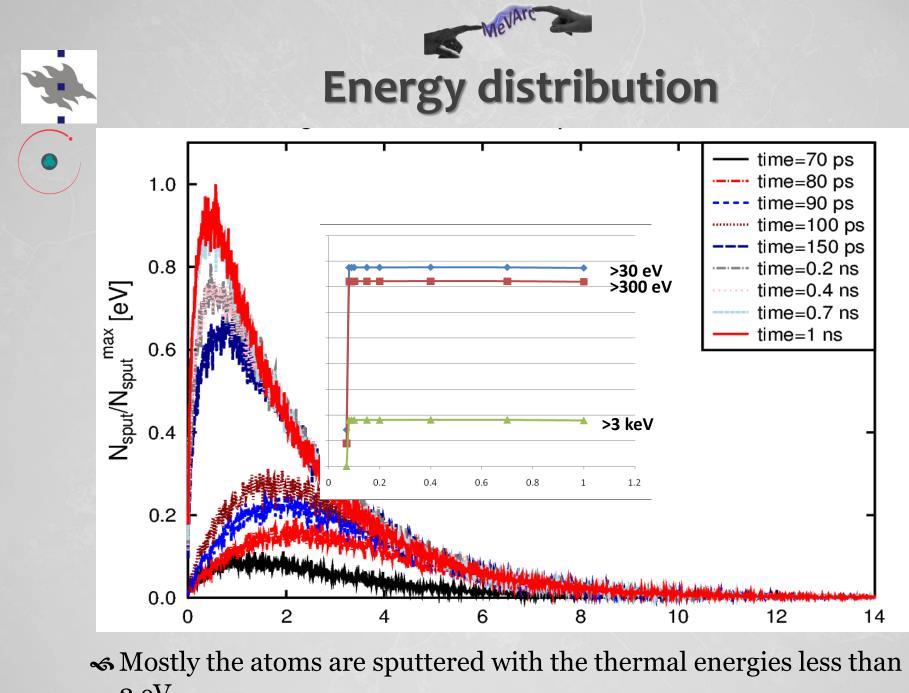


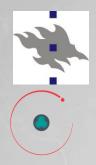
So We analysed a number of breakdown spots, there are many vacancies and Flyura Djural Brace and Brace and



Analysis of the sputtered atoms



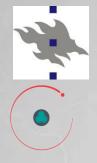






- Solution States with the states of the plasma onset and surface damage
- ✤ The model underlines the importance of mechanical properties of metal surfaces
- Solution The coupling of dislocation model and electric field effect resulted in "catastrophic" protrusion growth, which was not observed previously, but intuitively in line with field emission measurements from flat copper surfaces.
- Solution Analysis of the surface damage after craters cooled down reveals the presence of significant structural defects, which can participate in the formation of extended defects for future emitting spots.





Thank you for attention and valuable feedback!



